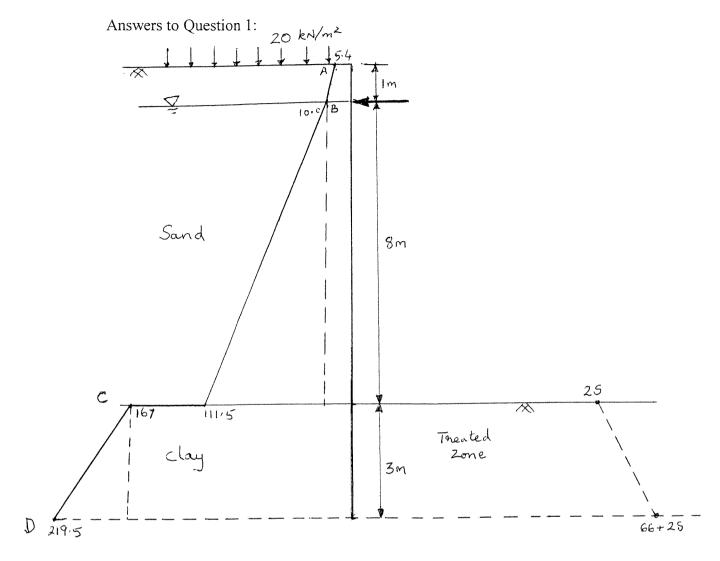
IB PAPER 8: SELECTED TOPICS-CRIBS

Part IB Selected Topics - Civil Engineering - June 2001



a) For Sand
$$Ka = \frac{1-5 \cdot n \phi}{1+\sin \phi}$$
 and $G_n' = Ka \sigma_{20}'$

$$\phi' = 35^{\circ} \qquad Ka = \frac{1-0.57}{1+0.57} = 0.27$$

Total horizontal pressure on = on + u where σ_h' = effective horizontal pressure and u = pose water pressure

For clay, assuming undrained behaviour

Total houzantal pressure on = 520 - 2 Cu (active)

where one = total vertical gressive and an is The undrained shear strength

At ground surface (Level A):



For equilibrium to be just maintained, Mp = MA

57 5+ 990 = 8035

S = 123.6 kPa

[10]

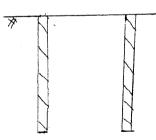
[In practice a Factor of Safety of at least 2 would be required, so that Mp = 2Ma] 57 S+990 = 2 x 8035 => S = 264.6 kPa

Question 2 Solution:

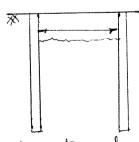
(a) Temporary sheet piling could be driven to support the ground, and the box Constructed within the sheet piles. There could be problems with driving the sheet giles with the Garse dense gravel, and noise and vibration would be a problem (particularly the vibration effects on Building B).

A preferable option would be diaphragm wills of Secant bored pile walls on the line of the box walls so that they can be in corporated into the permanent structure. Both types of wall have the advantage of being water light. (necessary because of the water present in the course sand and gravel strata).

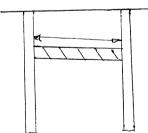
Either a 'bottom-up' sequence or a top-down' sequence could be adopted. Bottom-up' involves excavating to the base slab level, propping the wells with temporary props, and constructing the box starting with the base slab and then working apwards. Top-down involves construction of the roof slab of the box first and then working downwoods, as illustrated below:



a) Install walls

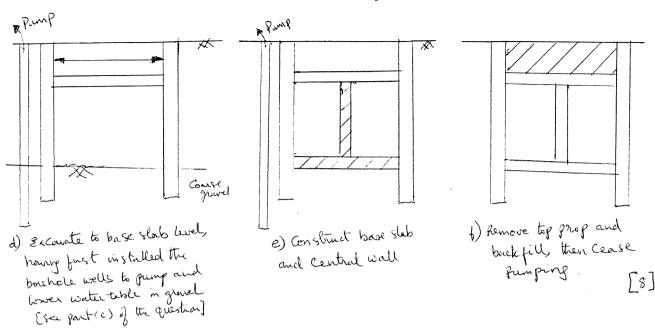


b) Excavate several meters and install temporary Prop



c) Excavate to the underside of the roof and cast roof slab (connecting it to the walls)





26) Axes of based tunnels at a depth of 10m unit weight of soil = 20 km/m3 undrained strength of Stiff clay = 100 kPa.

(without face support) = 10×20 = 2

This is very low, which means that the tunnels can be constructed without face support. The method could be open face turnelling machine + hining segments (precest concrete or spheroidal grapolite cost iron), or open face ex cavalian + sprayed Concrete linings (NATM - New Austrian Tunnelling Method).

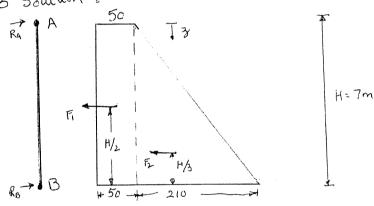
20) There is a need for the walls to be water tight to prevent water leakage from the Sand layer (see shetch(b)) and from the gravel layer. It is essential that the water level in the gravel layers is lowered by sumpry before the excavation is taken too close to the top of the gravel (see shetch(d)). The water bearing sound and gravel layers would not effect the tunnelling in the Stiff clay (provided turnel construction is relatively happid).

The ground movements are unlikely to affect Building A because it is on deep piled foundations (There may be minor horizontal movement of the nearest piles).

Building B Could be significantly affected by both vertical and horizontal grand movements. Possible techniques to prevent damage are : · Sustallation of tie rocks



- · under puring the building (of Jacking)
- · Counting of the Sand layer beneath the building to Create a stiff reft.
- · Compensation geouting (growting from growt tubes TAM's and mointory).
- 20) Instrumentation should be installed to mornitis:
 - · Settlement of both bouldings
 - · Settlement of the glound burface
 - « Houzontal movements of the grounds (inclinameters)
 - Horizontal movements of the walls in the case of cut-and-aver option (inclinometers in the walls)
 - · Sub Surface settlements of the glund (extensumeters) in the case of turnels.



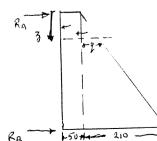
3(a)
$$F_1 = 50 \times 7 = 350 \text{ kN } @ H/2$$
 $F_1 + F_2 = 1085 \text{ kN}$
 $F_2 = \frac{1}{2} \times 210 \times 7 = 735 \text{ kN } @ H/3$

Take moments about B;

$$R_A \times H = F_1 \times H_2 + F_2 \times H_3 \implies R_A = \frac{F_1 + F_2}{2} = \frac{420 \text{ kN}}{3}$$

 $R_B = F_1 + F_2 - R_A = 1085 - 420 = \frac{665 \text{ kN}}{3}$

Derive expression for M at 3 and find maximum from dt = 0 3(b)At any digita 3: $\frac{3}{7} = \frac{2}{210}$ \Rightarrow $3 = 2 \times \frac{7}{210}$ or 2 = 303



$$M_{3} = 4203 - 50 \times 3 \times \frac{3}{2} - \frac{1}{2} \times 3 \times 303 \times \frac{3}{3}$$

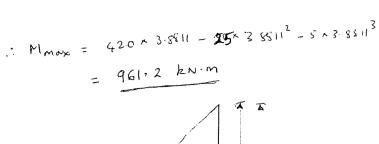
$$= 4203 - 253^{2} - 53^{3}$$

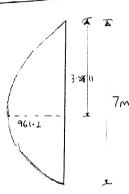
$$dM_{3} = 420 - 503 - 153^{2} = 0$$

$$\frac{dH_3}{d3} = 420 - 503 - 153^2 = 0$$

$$\frac{3}{3} + 3.333 - 28 = 0$$

$$\frac{3}{3} = -3.33 \pm \sqrt{3.33} + 4.29$$





[5]

Method 2: Find depth at which shear force = 0 and hen sub into equation of Manuels.

Shear
$$S_3 = 420 - 503 - \frac{1}{2} 3^3 303$$

 $= 420 - 503 - 153^2$
 $S_3 = 0$ when $420 - 503 - 153^2 = 0$
 $3^2 + 3.333 - 25 = 0$

$$4 \quad 3^{2} + 3.33 \quad 3 - 28 = 0$$

$$3 = -3.33 \quad 1 \quad \sqrt{3.33^{2} + 4 \times 28} = \boxed{3.8811} \text{ as before } .$$

$$d = \sqrt{\frac{M}{0.15 \, \text{km} \, \text{b}}} = \sqrt{\frac{961.2}{0.15 \times 40 \times 1000}} = 400 \, \text{mm}$$

Allow 50 mm Cover hence twell = 450 mm (minimum)

(Probably better to use 500 mm as to)

Reinforcement serume N.A at x =0.5

From Data shorts M= 0.87 by As d(1-x/2)

$$A_5 = \frac{M}{0.87 \text{ fy d}(1-4/2)} = \frac{961.2 \times 10^6}{0.87 \times 460 \times 400 \times (1-0.5)} = 8006 \text{ mm}^2$$

Check N.A Data sheet gives $x = 2.175 \frac{49}{4cu} \frac{A_s}{bd} \le 0.5$

Adopt 324 boors @ 100 mm spacing

4 bors @ 100 mm spacing

Check x
$$x = 2.175 \times \frac{660}{40} \times \frac{8042}{1000 \times 400} = 0.503 \approx 0.5 \text{ o.c.}$$



3 d) artalment is useful for reducing the amount of steel used in areas where the BM is reduced. When determing whether or not to autail steel one must anxider

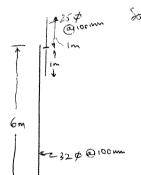
i) The standard length of 1/1 bars - would 6 m; It is expensive to have to cut hars + splice bars so try to contail at standard lengths.

ii) Ancholage length - must allow for anchorage bond length when determing the location of the effective area of sticl. Approximately 40 \$ can be used here.

In the s question 40 \$ = 40 x 32 = 1280 mm, so the bars must extend this for beyond the location at which they are required. For the wall of 7m height it will be necessary to spince the bars any way, unless 7m lengths are available.

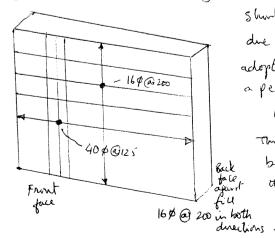
one common option is to alternate bons so that there is a halving of Ast at Im o 6m in this case. However after allowing for development lengths this would mean steel was effective from 2280 mm - 4720 m. a 2440 mm central zone. would need to check moment aparity at this location is adequate.

Here it seems more practical to use smaller bours for top zone



Say
$$25 \, \text{d}$$
 (a) 100 mm spacing = 4909 mm²
 $L_B = 40 \times 25 = 1000 \, \text{mm}$
 $\text{check} = 2 - 175 \times 460 \times 4909 = 0-307$

3 e) In theory there is no need for any horizontal bending it in the front face of this wall since the backing on the wall is assumed constant along the tunnel beight, hence there is no transverse bending set up. However, in fractice, some minimum steel



should always be provided to inhibit hacking due to temperature changes and shrunkage. Typically adopt a minimum of 500 mm²/m although codes give a percentage (013 / for fy = 460 Mps)

the 8 \$ \$ \$100 mm of 16 \$ \$200 mm. Adopt 16 \$ \$ 200 mm.
This should be flaced vertically and houzentally on back face and houzentally on the front face (invide the main flexural reinforce met)



3 b) Shear Capacity

$$v_c = 0.68 \left(\frac{100 \text{ Ab}}{\text{td}}\right)^{0.33} \left(\frac{400}{400}\right)^{0.25} \text{ MPa}$$
 $v_c = 0.68 \times \left(\frac{100 \times 5042}{400 \times 1000}\right)^{0.33} \left(\frac{400}{400}\right)^{0.25}$
 $v_c = 0.68 \times \left(\frac{100 \times 5042}{400 \times 1000}\right)^{0.33} \left(\frac{400}{400}\right)^{0.25}$

Applied Shear stees: $v_c = \frac{V}{bd} = \frac{k_b}{bd} = \frac{265 \times 10^3}{1000 \times 400} = 1.7 \text{ MPa}$
 $v_c > v_c = 1.7 \text{ Applied by accesse with the constant of the consta$

SECTION B: MECHANICAL ENGINEERING

4. a) Outer structure: strong, stiff material to provide strength and stiffness in bending and torsion. Must also provide resistance to knocks, protect the core from moisture, and serve as a base for decorative transfers, metal edges, and binding points.

Inner core: acts as a spacer for the outer structure, and provides damping. Need not be as strong or stiff as the outer structure, but must provide resistance against crushing, especially under the binding area.

b) From data book, p17:

Material	ρ	${f E}$
CFRP	1.5 Mg/m^3	50 GPa
Spruce (parallel to grain)	0.35 Mg/m^3	6 GPa

- N.B. 1) Don't use uni-ply CFRP, as structural properties are required in all directions.
 - 2) Choose E_{Spruce} parallel to grain, as the grain runs *along* the ski.

Then mass of ski =
$$1.95\{.08 \times .018 \times \rho_{CFRP} + .072 \times .014 (\rho_{Spruce} - \rho_{CFRP})\}$$

= $1.95 \text{ kg (to 3 s.f.)}$

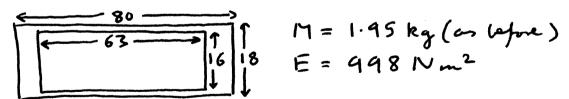
$$EI = \frac{0.08 \times 0.018^{3}}{12} E_{CFRP} + \frac{0.072 \times 0.014^{3}}{12} (E_{Spruce} - E_{CFRP}) = 1.22 \text{kNm}^{2} \text{ (to 3 s.f.)}$$

c)
$$\delta = \frac{W\ell^{3}}{48EI} = \frac{45 \times 9.81 \times 1.7^{3}}{48 \times 1.22 \times 10^{3}} = 0.037 \text{m}$$

i.e. a deflection of 37mm.

Net deflection from load is unaffected by either self-weight or camber, assuming the ski behaves as a linearly elastic structure.

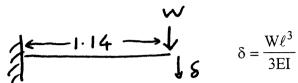
d) If no change in materials is allowed, the stiffness can be reduced by reducing the amount of CFRP at the top and bottom of the ski. Weight can be maintained (if required) by increasing the amount of CFRP at the sides of the ski, to compensate, e.g.



If the core can be changed, choose a material with a higher density, to allow weight to be maintained without adding CFRP to the sidewalls, as above. (It does not matter if the value of E is slightly higher, as the core only has a small effect on the overall bending stiffness of the ski.)

The new material would need to be crush-resistant in the binding area, and to have good damping and fatigue properties. A coefficient of thermal expansion similar to that of CFRP would also prevent the ski from de-laminating when its temperature changes.

- Using an equivalent mass-spring system to model the fundamental vibration mode of a ski allows the use of the response curves for single-degree-of-freedom damped systems, as shown in the Mechanics data Book - and also simplifies the modelling of tuned-mass dampers on the ski.
 - Forebody length = $\frac{1.5}{2.5} \times 1.9 = 1.14$ m



$$EI = \frac{W}{\delta} \times \frac{\ell^3}{3} = 1800 \times 0.494 = 889 \text{Nm}^2$$

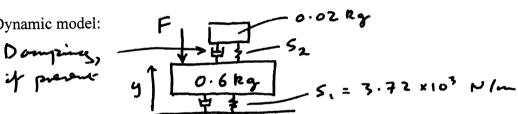
c) Actual mass of forebody = $\frac{1.5}{2.5} \times 2 = 1.2$ kg

$$\omega_n = 3.52 \sqrt{\frac{889}{1.2 \times 1.14^3}} = 78.7 \text{ rad / s} = \frac{12.5 \text{ Hz}}{1.2 \times 1.14^3}$$

For equivalent mass, $\omega_n = \sqrt{\frac{s}{m}} \Rightarrow s = m\omega_n^2$

Equiv. mass = 0.6 kg, so s = 3.72 kN/m

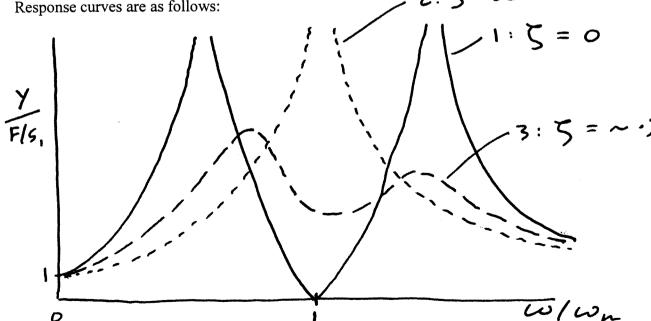
d) Dynamic model:



For constant tuning, the mass damper should have the same natural frequency as the original system, i.e.

$$s_2 = 0.02 \times 78.7^2 = 124 \text{ N/m (to 3 s.f.)}$$

Response curves are as follows:



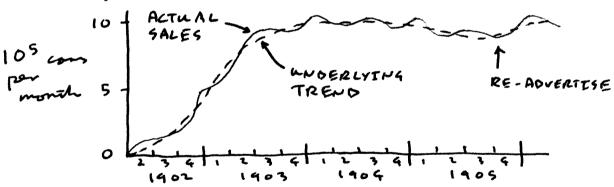
Optimal tuning gives the mass damper a slightly different natural frequency, to make the two 'humps' in curve (3) more equal in height.

- 6. A competent answer to this question would cover the following points:
 - a) Following BS7000, the principal stages in a product's development cycle are:
 - Initial trigger
 - Product planning to produce a project proposal
 - Feasibility study to produce a design brief
 - Design to produce a product definition
 - Development to refine the product definition
 - Production
 - Distribution
 - Consumption (including promotion)
 - Disposal (including questions of recycling)

The project has now completed the 'design' phase, and will move forward to development. Methods for production and distribution must now be planned, and the refined product definition should take into account the issues raised by these plans, as well as those of consumption and disposal / recycling. Patents should be applied for, on the new widget.

b) Sales will hopefully show a string initial growth after launch, which will weaken as the product reaches maturity. Eventual sales may reach the level of the non-widget beer (though we must expect the sales of that product to weaken). The sales graph will also show seasonal variations, with higher sales in summer and around Christmas. A final decline in sales should not occur for perhaps a decade, but further advertising campaigns may be necessary to prevent sales from weakening when new competitors are marketed.

Predicted sales pattern:



c) Eight important design specifications (excluding production aspects) are:

Geometry:	Must fit inside existing cans
Materials:	All materials must be food-approved
Safety:	Must be safe to open under all conditions
	Must not contain parts which could be swallowed
Cost:	Additional cost should not exceed about 12p per can
Operation:	Beer must taste as good as a draught beer
Legal:	Widget must not infringe existing patents
Life:	Cans should have the same shelf life as non-widget cans



- 6. d) Six important issues which must be addressed when planning the Manufacturing Strategy are:
 - 1 Will the widgets be produced in-house, or bought out?
 - Where will the new can-filling line(s) be? How will the raw materials (beer, cans, widgets, nitrogen &c.) be transported to this site, and how will the product be distributed afterwards? What space, machinery and personnel will be needed, and will the operators need special training?
 - 3 Is the proposed production method likely to infringe existing patents? Will licenses need to be negotiated? How will this affect profit margins?
 - 4 What kind of inspection and quality control will be needed?
 - How will the new widget be inserted into the cans? How will the cans and widgets be sterilised, and kept sterile until the beer has been added and the can has been closed?
 - 6 How will the product be marketed? What 'image' should it be given in the advertising campaign?

Q7 a) Torbofor engine produce thirst though a small velocity change by a large man flow. This gives a high propulsive efficiency as the waste exil- K.E. is lower.

Higher bypan stir results in a higher propulsive efficiency and a smaller high velocity core exit flow so can be much surished.

grieter.
Bypan ratio i limited by blade stress, hip speed being fixed. Also do not want loo low shaft speed as this makes ble LP Turbine design difficult.

- b) $P_{023} = 1.65 \times P_{02} = 1.65 \times 31 \text{ kfa} = 51.15 \text{ kfa}$ $T_{023}^{15eN} = T_{02} \left(\frac{P_{023}}{8}\right)^{\frac{8}{8}} = 245 \left|1.65\right|^{\frac{7}{3.5}} = 282.69 \text{ K}$ $\frac{2}{15eN} = \Delta T_{01DeAL} \Rightarrow T_{023} T_{02} = \left(\frac{15eN}{T_{023}} T_{02}\right)/2$ $\Delta T_{0ACTURL}$ $T_{023} = T_{02} + \left(\frac{15eN}{T_{023}} T_{02}\right)/2 = 245 + \left(\frac{282.69 245}{0.88}\right)/0.88 = \frac{287.83 \text{ K}}{2}$
- C) $T_{jb} = T_{023} \left(\frac{P_{jb}}{P_{023}}\right)^{\frac{8-1}{8}} = 287.83 \left(\frac{20}{51.15}\right)^{\frac{7}{3.5}} = 220.10 \text{ k}$ $V_{jb}^{2} = 2C_{p} \left(T_{023} T_{jb}\right) = 2\times1010 \left(287.83 220.10\right) \quad \underline{V_{jb}} = 369.9 \text{ m/s}$ $M_{jb} = V_{jb} / \sqrt{8RT_{jb}} = 369.9 / \sqrt{1.4.287.220.10} = 1.244$
- d) To23 = 287.83 k To3 = 751 k Po23 = 51.15 kfa $Po3 = 22 \times Po23 = 22 \times 51.15 = 1125.3 \text{ kfa}$ To4 = 1500 k Po4 = Po3 = 1125.3 kfaHP TURGINE WORK = CORE COMPRESSOR WORK => CPATO => $\Delta T_0 = \Delta T_0$ To48 To45 = To3 To23 To45 = To4 (To3 To23) = 1500 (751 287.83) = 1036.83 k $2_{150} = \Delta T_0 \text{ Actal } \Rightarrow To4 To45 = (To4 To45)/7$ To45 = To4 (To4 To45)/7 = 1500 (1500 1036.83)/0.90 = 985.37 k $Po45 = Po4 \left(\frac{To45}{To45}\right)^{\frac{1}{2}} = 1125.3 \left(\frac{985.37}{1500}\right)^{3.5} = \frac{258.63 \text{ kfa}}{To45}$

$$\begin{array}{ll} (Q7 \ cont \ e...) \\ 2_{15eN} &= \Delta T_{OACTUML} \ =) \ T_{O45} - T_{o5}^{15eN} = (T_{O45} - T_{o5})/2 \\ \hline \Delta T_{O 1DEML} \\ T_{O5} &= T_{O45} - (T_{O45} - T_{o5})/2 = 1036.83 - (1036.83 - 631.95)/0.92 \\ T_{O5} &= 594.5 \ K \\ P_{O5} &= P_{O45} \left(\frac{T_{O5}^{12eN}}{T_{O45}}\right)^{\frac{2}{5}} - 260.60 \left(\frac{594.5}{1038.83}\right) = \frac{36.90 \ kla}{1038.83} \end{array}$$

f)
$$T_5 = T_{05} \left(\frac{P_5}{P_{05}} \right)^{\frac{1}{8}} = 631.95 \left(\frac{20}{36.9} \right)^{\frac{1}{3}.5} = 528.69 \text{ K}$$

$$V_5^2 = 2C_p \left(T_{05} - T_5 \right) = 2 \times 1010 \left(631.95 - 528.69 \right)$$

$$V_5 = 452 \quad m/5$$



(8) a) As the fan has a much larger diameter the rotational speed must be much lover to maintain a similar tip much number. Hence a two-shaft arrongement allows both fan and care compressor to ver at similar tip much numbers.

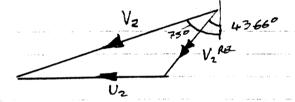
b) The stage loading in the compressor must be lower (~0.4) than in the tembrine (~2.0). Hence need more stages to achieve the necessary work input. Stage loading must be lower in the compression process as the blade boundary layers must flow against an adverse pressure godient across the stage.

c)
$$V_0^{RR} = V_0 - U = \frac{V_0^{RR}}{V_X} = \frac{V_0}{V_X} - \frac{U}{V_X} = \frac{1}{2} \tan x^{RR} = \tan x - \frac{1}{2}$$

ROTOR INCET $Z_2 = 75^\circ$ $\tan Z_2^{NR} = \tan 75^\circ - \frac{1}{0.36} \implies Z_2^{RE} = 43.66^\circ$ (+ve $\Rightarrow co-RoT$)

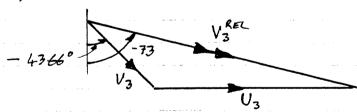
ROTOR EXIT $d_3^{REL} = -73^\circ$ $\tan d_3 = \tan(-73^\circ) + \frac{1}{100} \Rightarrow d_3 = -26.25^\circ$ (-ve 3 control-Rot)

INLET :



ROTOR

ROTOR DUTLET:



d) $V_x = 210 \text{ m/s}$ $V_{02} = V_x t_{AN} d_2 = 210 t_{AN} 75^\circ = 783.73 \text{ m/s}$ $V_{03} = V_x t_{AN} d_3 = 210 t_{AN} (-26.28) = -103.56 \text{ m/s}$ U = 210 (0.36 = 583.33 m/s) $W_x = U(V_{02} - V_{03}) = 583.33 (783.73 - -103.56) = 517.583 \text{ kJ/kg}$

 $\Delta T_0 = W_{\star}/c_p = 517.583/1.010 = 512.46 K$ $T_{03} = T_{02} - \Delta T_0 = 1850 - 512.46 = 1337.54 K$

f)
$$V_{x3} = 210 \text{ m/s}$$
 $V_{3} = \sqrt{V_{x3}^{2}} + V_{63}^{2} = 234.15 \text{ m/s}$
 $V_{03} = -103.56 \text{ m/s}$
 $V_{3} = T_{03} - V_{3}^{2}/2c\rho = 1337.54 - 234.15^{2}/2\times1010 = 1310.40 \text{ K}$

$$P_{3} = P_{03} \left(\frac{T_{3}}{T_{03}}\right)^{\frac{8}{8}-1} = 266.323 \left(\frac{1310.40}{1337.54}\right)^{3.5} = \frac{247.88 \text{ k/a}}{1337.54}$$

$$\rho_3 = \frac{\rho_3}{RT_3} = \frac{247.88 \times 10^3}{287 \times 1310.40} = 0.6591 \text{ kg/m}^3$$

$$A_3 = \dot{m} = 50 = 0.3612 \, m^2$$
 $P_3 V_{*3} = 0.6591 \times 210$

```
1/2
(09) a) T, = To, /(1+ = M,2) = 248/(1+0.2.0.852) = 216.69 K
          P, = Po, / (1+ = M2) = 31/(1+0.2.0.852)3.5 = 19.33 kPa
                                                                                        CRUISE
         V = M, JYRT = 0.85 /1.4 x 287 x 216.69 = 250.81 m/s
  b) \frac{\dot{m}\sqrt{C_{p}T_{01}}}{P_{0}} = f_{n}\left(8, \frac{T_{04}}{T_{01}}\right) & \frac{\rho_{03}}{\rho_{01}} = f_{n}\left(8, \frac{T_{04}}{T_{01}}\right)
    SAME PO3/PO1 => T_{04} = T_{04} To1 = 288k

T_{01} | STAT To1 | CRUISE PO1 = 101 kPa
                                                                         in = 10 kg/s
    To4/cr = To1/cr To4/ = 248.1800 = 1550 K
Ta/527 288 @CRUS
     SAME CONDITIONS => MIJCPTOI = MIJCPTOI | POI ARE CRUSE
        \Rightarrow \dot{m}|_{CRV} = \dot{m}|_{STA7} \frac{\sqrt{Toi}}{f_{01}} \times \frac{f_{01}}{\sqrt{Toi}}|_{CRV} = 10 \frac{288 \times 31}{248} = \frac{3.308 \text{ kg/s}}{248 \times 101} = \frac{3.308 \text{ kg/s}}{CCRUISE}
  c) To4 = 1.27
      T_{05}|_{CRU} = T_{04}|_{CRU} \times \frac{1}{1.27} = \frac{1550}{1.27} = \frac{1220.47}{1.27}
      CHOKED NOZZLE => m VCPTOS = 1.281
        |P_{OS}|_{CRUDE} = \frac{|\vec{m}|\sqrt{CpT_{OS}}|}{|A_{5}|\sqrt{1281}|} = \frac{3.308\sqrt{1010.1220.47}}{|O.016|} = \frac{179.19}{|CRUISE}
       TNOZZE = TO5/(1+ 1 MNOZZ) = 1220.47/(1+0.2.1) = 1017.06 K @CRUISE
        VNOZZLE = M J8RT = 1.0 JI.4.287 × 1017.06 = 639.26 mls @CRUISE
       PNOZZLE = Pos/(1+ = Mivozz)3.5 = 179.19/(1+0.2×12)3.5 = 94.66 KPa @CRUISE
  d) Simple converget norze so MNOZZE = 1 (as choked). However the
     have in-contained expansion downstream to a higher Noch.
 e) GROSS THRUST = MVNOZZE + (PNOZZEB - PAMB) ANDEZEE
                                           + PNOZZLE ANOZZLE ) - (PAMB ANOZZLE)
       POI POI
```

fn (8, Tou/Tox)

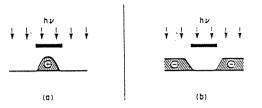
for (flight speal)

```
(Q9 cont)
e)cont)
GROSS THRUST = mi VNOZZIE + (PNOZZ - PAMB) ANOZZ
= 3.308 x 639.26 + (94.66 - 19.33) x 103 x 0.016
= 3319.95 N
```

POSITIVE AND NEGATIVE

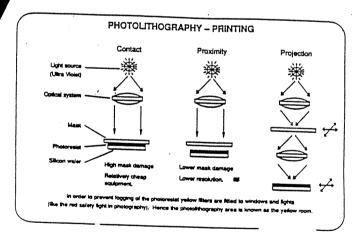
POSITIVE AND NEGATIVE RESIST

As mentioned previously photoresist is a radiation sensistive compound. They can be calssified as **positive** or **negative**, depending upon how they respond to radiation.



cross section of the resist image after development (a) Positive photoresist. (b) Negative photoresist.

For positive resists the exposed regions become more soluble and thus more easily removed in the development process. The net result is that the patterns formed in the positive resist are the same as those on the mask. For negative resists the exposed regions become less soluble and the patterns formed in the negative resist are the reverse of the mask patterns (see above figures).



PROXIMITY/CONTACT PRINTING

is characterised by getting the mask as close as possible to the surface of the wafer to minimise errors due to dispersion of the light beam and vibration.

In some cases the mask may actually touch the wafer (contact printing). Such machines are relatively cheap but both wafer and mask will suffer some mechanical damage during exposure.

TYPES OF LITHOGRAPHY AND THEIR CAPABILITIES

FOUR PARAMETERS DETERMINE THE LITHOGRAPHIC PERFORMANCE

RESOLUTION---- THE MINIMUM FEATURE SIZE THAT CAN BE PRODUCED REPEATABLY

REGISTRATION---- HOW CLOSELY SUCCESSIVE MASK LEVELS CAN BE OVERLAID

THROUGHPUT---- NUMBER OF WAFERS THAT CAN BE EXPOSED IN 1 HOUR.

DEPTH-OF-FOCUS (FIELD)---- THE REGION OVER WHICH THE IMAGE REMAINS IN FOCUS. IF VARIATIONS IN HEIGHT OF A SURFACE ARE GREATER THAN THE DEPTH OF FIELD THEN GET DEGRADATION OF THE PATTERN.

THE MAJORITY OF IC PRODUCTION IS CARRIED OUT USING OPTICAL SYSTEMS. THAT OPERATE IN THE UV

PROJECTION PRINTING

This process removes the mask from the surface of the wafer and projects the image from the mask onto the wafer. In order to provide high quality optics the mask and wafer are moved together through a well collimated beam or spot of light. The machine cost is therefore higher than that of a proximity type. The wafer and mask are not damaged because they are not close to one another and this obviously improves mask life.

The optical elements in most modern projection printers are so perfect that their imaging characteristics are dominated by diffraction effects rather than by lens aberration - diffraction limited systems. The resolution of a diffraction limited printer is roughly 0.5 (λ /NA) where NA is the numerical aperture of the projection optics and λ is the wavelength. The depth of focus of the system is approx. given by λ /(NA)². i.e. a high resolution (large NA) is achieved at the expense of depth of focus.



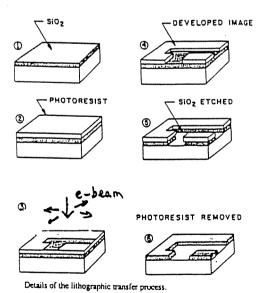
Current production line systems are capable of 0.3 micron resolution, 0.1 micron registration and a throughput of approx. 20 off 150 mm diameter wafers per hour.

Far UV research systems are capable of approx. 0.25 micron resolution and registration of approx. 0.1 microns.

Electron beam systems - they are currently able to operate at resolutions down to 20 nm but will only have a minimal throughput and therefore these would only be used for very specialist applications. For sytems with resolutions of approx. 0.25 micron a throughput of approx 0.5 wafer per hour would be possible. E-beam systems are generally used to produce the photomasks but can be used directly write on wafers.

X-ray lithography systems have approx. 0.13 mircrons resolution and 0.13 microns registration but are still a long way from the production line.

32



by dirt with low atomic number, dirt on the mask does not print as a defective pattern on the resist. Masks however are still a problem.

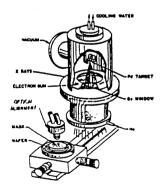
ELECTRON BEAM WRITING:

Electron beam direct writing of a wafer is a technique where the photoresist is exposed by a beam of electrons that is steered to produce the pattern needed. No mask is used. Consequently the machine is very versatile and multiple designs can be mixed on one wafer. Used for fast turn round of new designs etc but no good for mass production.

35

X-RAY LITHOGRAPHY:

This is an extension of optical proximity printing in which the exposing wavelength is in the 4 - 50 A range. Because x-ray optical elements are not yet available, x-ray lithography is limited to shadow printing. System is as shown below.



The mask and wafer are separated by about 40 microns. The full wafer is exposed in about 1 minute. The primary reason for developing x-ray lithography is the possibility of achieving high resolution and high through put at the same time. Also since x-rays are not absorbed

The step and repeat camera projects the reticle onto a portion of the plate's surface and shrinks the image to 1/10 the size of the pattern on the reticle. The plate is moved so that another exposure is made adjacent to the first one, and the process is repeated, stepping across and down the plate until the whole surface is covered. Usually a rectangular area is completely covered with the pattern (but see the section on process control and plug dice), but in some cases the array will be made circular (like a wafer).

Des défents on restation on deflet of

d) Assuming a vector scan:

The mox over of exposure/sec

= $40 \times 106 \times 0.05 \times 10^{-6} \times 0.05 \times 10^{-6}$ = $10^{-7} \text{ m}^2/5$ That are exposed = $20\% \text{ TF } r^2$ = $20 \times 17 \times (0.1)^2 = 0.0063 \text{ m}^2$ $20 \times 10^{-7} \text{ m}^2/5$

=) $^{10}h_{10} = \frac{63000}{3600} = 17.4 h_{10}$

This is a very long time to maintain stuble environment and demostrates the improducally of co-beam writing the most applications.

Crib

Gauss theorem.

$$D.A = N.e.Ah$$

$$E = Neh/\epsilon$$

$$V_{\alpha} = -\int E.dh$$

$$V_g = Neh^2/[2\epsilon]$$

[b]
$$N = 2V_g \epsilon/eh^2 = 2x0.5x0.8.10^{-10}/1.6.10^{-19} \times 10^{-6} \times 10^{-6} = 5.10^{20} \text{ m}^{-3}$$
 (denote)

[c]
$$v = \mu E$$
, $v=L/t$. $V_d=E.L$ $\therefore L^2 = \mu V_d t$

$$L^2 = 0.4 \times 2 \times 5.10^{-12} = 4.10^{-12}$$
. L=2.10⁻⁶ m.

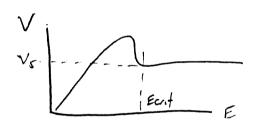
[d]
$$W = 50.L = 10^{-4} \text{ m}.$$

$$R = \rho L/A = L/[Ne\mu Wh] = 2.10^{-6} / [5.10^{20}x1.6.10^{-19} \times 0.4 \times 10^{-4} \times 10^{-6}] = 625 \text{ ohm.m}$$

[e] C' = Q'/
$$V_g$$
 = Neh/ V_g = Neh/[Neh²/2 ϵ] = 2 ϵ /h

$$C' = 2 \times 0.8.10^{-10}/10^{-6} = 1.6.10^{-4} \text{ F.m}^{-2}$$

Q 12/



b] Scattering limited velocity is the maximum carrier velocity. It is caused by intense scattering by phonons which stops carriers accelerating to larger volecities.

C]
$$U = 0.5 \text{m} \cdot \text{v}_s^2 = 0.5 \text{x} \ 0.1. \ 9.11.10^{-31} \ 10^5 \ .10^5 = 4.55.10^{-22} \ \text{J}$$
, $4.55.10^{-22}/1.6.10^{-19} = 2.85.10^{-3} \ \text{eV}$

D]
$$m_e^* v_e^2 / m_h^* v_h^2 = 1$$
. $V_h = v_e / \sqrt{3} = 5.7710^4 \text{ m.s}^{-1}$.

E]
$$\mathbf{v}_s = \mu E$$
 $E = 10^5/0.1 = 10^6 \text{ V/m}$. $L = V/E = 1.5/10^6 = 1.5.10^6 \text{ m}$.

F]
$$t = L/v_s = 1.5.10^{-6}/10^5 = 15.10^{-12} s.$$

G]
$$J = Nev_s = 2.10^{21} \times 1.6.10^{-19} \times 10^5 = 3.2.10^7 \text{ A/m}^2$$
.



Part I Elective: Information Engineering "An Architecture for Wearable Computing" Answer Sheet (2 Questions Set by PMW)

(a) Total of 7 marks.

(i) The final part (and first mark) is easy. The mechanism used is the *system call* or *software trap* (either wording is acceptable).

For the other two marks, they should have said something sensible about the differences between user mode and supervisor mode, but should include something about the level of access to system resources. For example:

<u>User Mode</u>: Mode in which the users application code runs. As there may be multiple user applications running as separate processes, user mode is constrained to prevent interference with other processes. This means it is limited to not being able to access hardware resources, or to have unlimited access to memory space.

<u>Supervisor Mode</u>: Mode in which the operating system runs. Low-level access to system hardware is allowed as have full access to memory space.

Clearly, some of the features of supervisor mode could also be worded as limitations of user mode.

- (ii) One mark each (up to a maximum of four marks) for any of the following:
 - 1. Controls/limits usage of system resources by user processes (allocates resources to user processes and reclaims them when finished)
 - 2. Responds to events associated with these resources on behalf of the user to maximise system performance.
 - 3. Hides complexity (controlling devices too complex for the user). Provides useful services to the user applications
 - 4. Abstraction: Provides independence from specific device characteristics
 - 5. Want to create virtual high-level devices (files etc) on top of raw device
 - 6. Prevent interference when more than one user (protection)
 - 7. Ensure fairness when more than one user (scheduling of devices)

As before, they do not have to get the exact wording (which is why a number of alternatives have been given). If they show an understanding of the general idea of any of these, then they should get the mark.



- (ii) Marks are approximately one mark for identifying the mechanism and one mark for the explanation (giving two marks per peripheral device):
 - 1. Keyboard entry: An interrupt peripheral. User input is orders-of-magnitude slower than the CPU speed, so polling would be very wasteful. Similarly, as each key press generally generates an action, DMA is not appropriate at all.
 - 2. Sampling an A/D converter: The clue is in the question with the word 'sampling'. As you generally want to just check the instantaneous value, this is best implemented as a polled peripheral. DMA is only appropriate if you wanted to autonomously log the value over time (and given the slow changes, you probably wouldn't even choose DMA then).
 - 3. Disk Interface: We are dealing with blocks of data from a fairly fast peripheral. Therefore, the most sensible option is DMA. A polled mechanism would be a heavy drain on CPU resources, while interrupt driven mechanism would generate a lot of interrupt traffic and may not be able to provide low enough latency.
 - 4. RS232 Serial Interface: The peripheral is quite slow (but faster than a keyboard). DMA isn't really appropriate as it is a character-based device. Polling may be used, but may miss characters and will waste a lot of CPU resources in waiting for device status to change. Interrupts are the best mechanism.
 - If they do suggest polling, you could deduct one mark (unless they are a bit clever and suggest putting a FIFO in the peripheral though this isn't covered by the course).

An example of where the more creative candidate may differ from my suggestion is the battery voltage. They may say that you can provide a threshold you could generate an interrupt when it crosses the threshold. If anyone does do this, I'd even be tempted to go as far as to give a bonus mark!



4. (a) Total of 11 marks.

14

For each of the following OS features, I've put down key phrases. If they mention enough of them, then they should get the marks.

- (i) Process is a program plus the resources it needs to run it
 Multiprocessing system has many processes active simultaneously
 Need mechanism to spawn new processes and switch between them
 Can cooperatively yield to another processor (wait()).
 Otherwise, switch when time-slice has expired (pre-emptive)
 Switch when blocked waiting for IO to complete (better CPU usage)
 Scheduling can be round-robin or based on priorities
 Higher priority to IO bound than CPU bound (better throughput)
 (Up to 3 marks)
- (ii) Provide protection between independent process memory spaces
 Want to appear that each process has entire address space available
 Don't want entire program in memory at the same time (swapping)
 Allow process to use more memory than physically available (paging)
 Implements page table to translate logical to physical addresses
 Pages also have protection bits (read/write, read only etc)
 Need to handle page replacement (various replacement mechanisms)
 Dirty bit used to mark when page written to and needs storing back
 Change amount of pages allocated per process depending on miss rate
 (Up to 3 marks)
- (iii) Independence from specific hardware device characteristics
 Simpler interface for the user (direct access complex for users)
 Create virtual higher-level devices (streams, files etc)
 Prevent access interference if multiple users
 Provide fair access to resources when competing processes
 (Up to 2 marks)

Again, if they get three or more of the hardware features listed below, the get the three remaining marks.

The features provided by the processor include:

Interrupts to respond to peripheral events
User/supervisor modes to control resource access
Software traps/system calls to switch between modes
Hardware IO registers for peripheral control

Supporting hardware includes:

Timer interrupts are required for pre-emptive scheduling Memory Management Unit (MMU) for memory protection MMU also handles logical to physical address translation Translation Look-aside Buffer (TLB) speeds up page translation



(c) Total of 3 marks.

This is covered at the end of the course, so should be fresh in their minds. If they mention three or more of them, they get the marks.

Power features:

Switch CPU off when waiting for peripheral interrupt or DMA Shutdown sections of the CPU not being used (e.g. multiply unit) Peripherals powered down when not in use (device management) Shutdown device when not in use for a while (wakeup button)

Reduce IO bandwidth or transmit power Limit access to power intensive operations (e.g. FLASH writing)

Scale processor speed based on current load

Not dealt with in the course, but they may mention if they have used a laptop:

Reduce screen brightness when not on mains Step CPU speed down when not on mains

I guess these are equally valid, but I would suggest either of them counts as one mark only (they shouldn't get two marks for mentioning both of these).



015

Information Engineering Elective 2000 A x

- Infra-red does not go through walls but is vulnerable to interference from light sources (sunlight, fluorescent). Cheap transmission and reception devices are available.
 - Radio penetrates walls but can work quite fast, vulnerable to radio interference, cheap devices not yet available. Ultrasonic intrinsically slow.
- b To minimise energy usage pulse position modulation is best. Pulse can be shaped, cheap timing devices are available to measure time to next pulse, many encodings of the meaning of the time differences between pulses possible, binary probably best.
- c Collision avoidance by synchronisation, collision resolution by protocol. Synchronisation by using a unique marker in the modulation, otherwise a special/unique bit pattern. Use synchronisation to arrange transmissions are not at the same time.
 - Resolution depends on whether system is master-slave or peer-to-peer. For master-slave master receives bids and gives out transmission permissions. For peer-to-peer a distributed algorithm is required with each unit observing passing traffic and making a decision when to transmit.
 - A simple version is to randomise the (re)transmission interval, for example by modifying it depending on how much light is falling on the device.
- d Packets can contain a source and destination address in which case the system is connectionless. May take longer to process but is self-contained. Otherwise the packet can have solely a connection identifier where each communication path has been set up in advance. This is called connection-oriented and can be good for making fast decisions when handling packets.
- e Using infra-red is not likely to give high speeds, particularly if the system is diffuse and the signal needs to be decoded even after it bounces from a wall. So maximum effective data rate will be a few kilobits/sec.
- If receivers are associated with rooms it is extremely unlikely that a receiver will pick up transmissions from another room. Hence there will be very few false positives and the quality of the location information will be high. However clothes can obscure the transmitter.